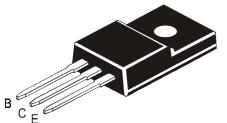


## PNP SILICON PLANAR POWER TRANSISTOR

CJF6107



TO-220FP Fully Isolated Plastic Package

# General Pupose Amplifier and Switching Applications.

#### ABSOLUTE MAXIMUM RATINGS.

DESCRIPTION	SYMBOL	VALUE	UNIT
Collector Base Voltage	V <sub>CBO</sub>	80	V
Collector Emitter Voltage	V <sub>CEO</sub>	70	v
Emitter Base Voltage	V <sub>EBO</sub>	5	V
RMS Isolation Voltage (for 1sec,R.H.	(1) V <sub>ISOL</sub> (a)	3500	V <sub>RMS</sub>
<30%, T <sub>A</sub> =25°C )	(b)	1500	V <sub>RMS</sub>
Collector Current - Continuous	I <sub>C</sub>	7	A
Peak	-	10	А
Base Current	I <sub>B</sub>	3	А
Total Power Dissipation @ Tc=25°C	P <sub>D**</sub>	34	W
Derate Above 25°C		0.27	W/ºC
Total Power Dissipation @ Ta=25°C	P <sub>D</sub>	2	W
Derate Above 25°C		0.016	W/ºC
Operating and Storage Junction	T <sub>i,</sub> T <sub>stg</sub>	- 65 to +150	°C
Temperature Range	,, <u>-</u>		
THERMAL RESISTANCE			
From Junction to Case	R <sub>th (j-c)**</sub>	3.7	°C/W
From Junction to Ambient	R <sub>th (j-a)</sub>	62.5	°C/W
Lead Temperature for Soldering Purpose	TL	260	°C

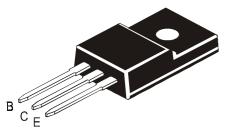
\*\*Measurement made with thermocouple contacting the bottom insulated mounting surface (in a location beneath the die), the device mounted on a heatsink with thermal grease and a mounting torque of <u>>6</u> in.lbs.

(1) RMS Isolation Voltage : (a) 3500 V<sub>RMS</sub> with Package in Clip Mounting Position (b) 1500 V<sub>RMS</sub> with Package in Screw Mounting Position (for 1sec, R.H.<30%, Ta=25°C; Pulse Test: Pulse Width  $\leq$ 300µs, Duty Cycle $\leq$ 2%)

#### ELECTRICAL CHARACTERISTICS (Tc=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNIT
Collector Emitter sustaining Voltage	V <sub>CEO (sus)</sub> *	I <sub>C</sub> =100mA, I <sub>B</sub> =0	70		V
Collector Cut off Current	I <sub>CES</sub>	V <sub>CE</sub> =80V, I <sub>B=</sub> 0		1	μA
	I <sub>CEX</sub>	V <sub>CE</sub> =80V, V <sub>EB</sub> (off)=1.5V		1	μA
Emitter Cut off Current	I <sub>EBO</sub>	V <sub>EB</sub> =5V, I <sub>C</sub> =0		1	μA

### PNP SILICON PLANAR POWER TRANSISTOR



TO-220FP Fully Isolated Plastic Package

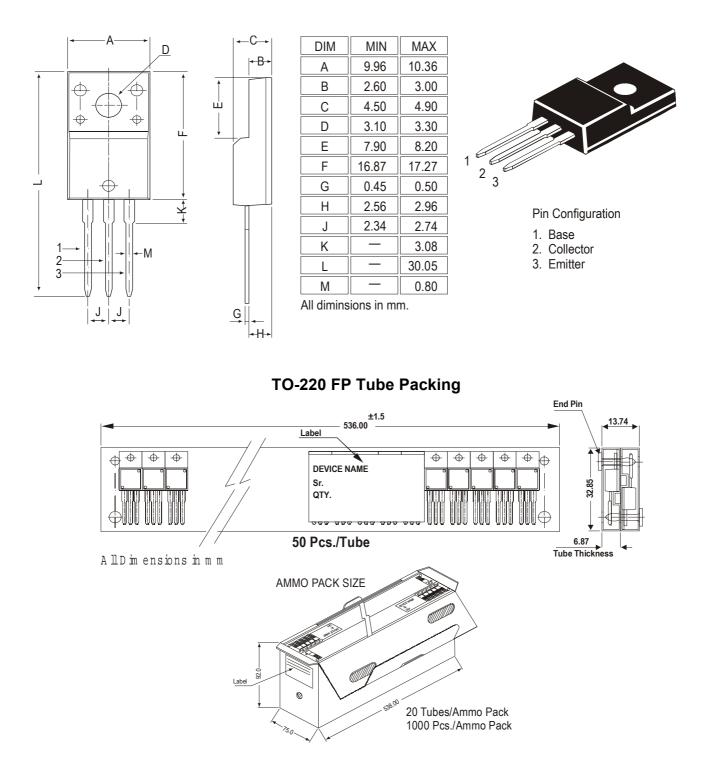
#### ELECTRICAL CHARACTERISTICS (Tc=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNIT	
Collector Emitter Saturation Voltage	V <sub>CE(Sat)</sub> *	I <sub>C</sub> =7A, I <sub>B</sub> =3A		2	V	
Base Emitter on Voltage	V <sub>BE(on)</sub> *	$I_{C}=7A, V_{CE}=4V$		2	V	
DC Current Gain	h <sub>FE</sub> *	I <sub>C</sub> =2A, V <sub>CE</sub> =4V	30	90		
		$I_{C}$ =7A, $V_{CE}$ =4V	5			
DYNAMIC CHARACTERISTICS						
Small Signal Current Gain	h <sub>fe</sub>	I <sub>C</sub> =0.5A, V <sub>CE</sub> =4V,f=50kHz	20			
Output Capacitance	C <sub>ob</sub>	$V_{CB}$ =10V, $I_{E}$ =0, f=1MHz		250	pF	
Current Gain - Bandwidth Product	f <sub>T (2)</sub>	I <sub>C</sub> =500mA,V <sub>CE</sub> =4V,f=1MHz	4		MHz	
* Pulse Test: Pulse Width <300μs, Duty C	ycle <u>&lt;</u> 2 %					

(2) f<sub>T</sub>=Ih<sub>fe</sub>I.f<sub>T</sub> Test

## TO-220FP Fully Isolated Plastic Package

# **TO-220FP Fully Isolated Plastic Package**



# **Packing Detail**

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
T0-220FP		396 gm/200 pcs 135 gm/50 pcs	3" x 7.5" x 7.5" 3.5" x 3.7" x 21.5"		17" x 15" x 13.5" 19" x 19" x 19"	16K 10K	36 kgs 28 kgs

TO-220FP Fully Isolated Plastic Package

#### Disclaimer

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